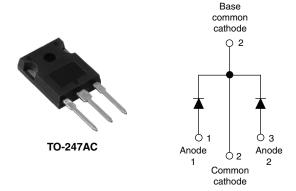


### Vishay Semiconductors

### Hyperfast Rectifier, 2 x 40 A FRED Pt®



PRODUCT SUMMARY				
Package	TO-247AC			
I <sub>F(AV)</sub>	2 x 40 A			
$V_{R}$	200 V			
V <sub>F</sub> at I <sub>F</sub>	1.02 V			
t <sub>rr</sub> (typ.)	34 ns			
T <sub>J</sub> max.	175 °C			
Diode variation	Common cathode			

#### **FEATURES**

- · Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Compliant to RoHS Directive 2002/95/EC



#### **DESCRIPTIONS/APPLICATIONS**

VS-80CPU02-F3 series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of welding, SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Repetitive peak reverse voltage	$V_{RRM}$		200	V
Average rectified forward current $\frac{\text{per leg}}{\text{total device}}$		I <sub>F(AV)</sub> T <sub>C</sub> = 145 °C	40	
	IF(AV)		80	Α
Non-repetitive peak surge current per leg	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	330	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS M		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	200	-	-		
	V <sub>F</sub>	I <sub>F</sub> = 40 A		0.94	1.02	]	
Forward voltage		I <sub>F</sub> = 40 A, T <sub>J</sub> = 150 °C	-	0.80	0.90	V	
		I <sub>F</sub> = 80 A	-	1.07	1.20		
		I <sub>F</sub> = 80 A, T <sub>J</sub> = 150 °C	-	0.97	1.08		
	$V_R = V_R$ rated	-	-	5			
Reverse leakage current I <sub>R</sub>		$T_J = 150 ^{\circ}\text{C}$ , $V_R = V_R$ rated	-	-	500	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V - 120 -		pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 3.5 - nH		nH			

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### VS-80CPU02-F3

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	34	ı		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	33	-	ns
	T <sub>J</sub> = 125 °C		-	54	-		
Peak recovery current I <sub>RRM</sub>		T <sub>J</sub> = 25 °C	$I_F = 40 \text{ A}$ $dI_F/dt = -200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	3.4	-	^
	IRRM	T <sub>J</sub> = 125 °C		-	8	-	A
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	56	-	nC
	T <sub>J</sub> = 125 °C		-	216	-	110	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	0.46	0.70	
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	40	°C/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.3	-	
Weight			-	6.0	-	g
vveignt			-	0.21	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC	80CPU02			



## Hyperfast Rectifier, 2 x 40 A FRED Pt®

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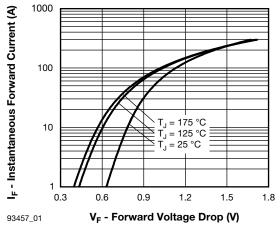


Fig. 1 - Typical Forward Voltage Drop Characteristics

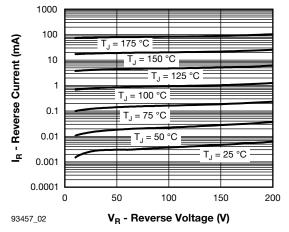


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

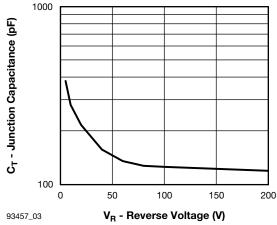


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

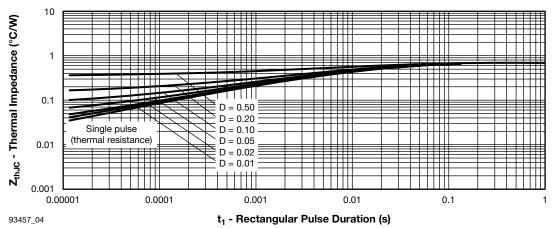


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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## Hyperfast Rectifier, 2 x 40 A FRED Pt®



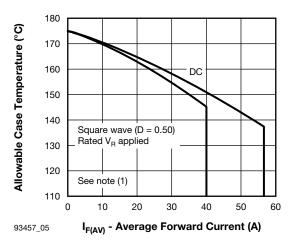


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

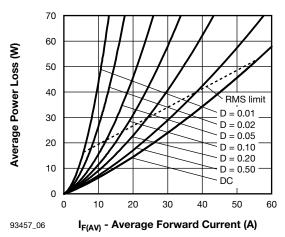


Fig. 6 - Forward Power Loss Characteristics

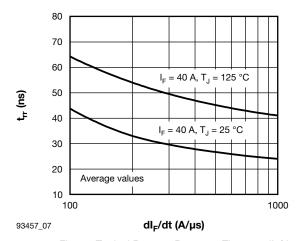


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

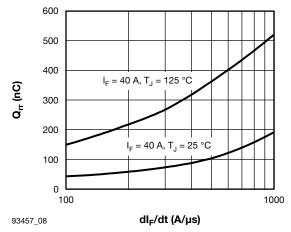


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 



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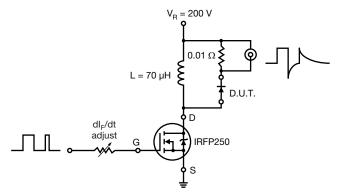
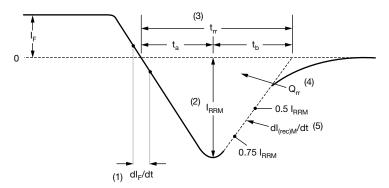


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions

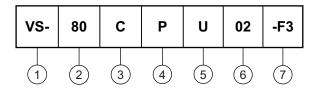
Vishay Semiconductors

## Hyperfast Rectifier, 2 x 40 A FRED Pt®



#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (80 = 80 A)

Circuit configuration:

C = Common cathode

**4** - P = TO-247AC

5 - U = Ultrafast rectifier

6 - Voltage rating (02 = 200 V)

7 - Environmental digit:

-F3 = RoHS compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-80CPU02-F3	25	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95223			
Part marking	www.vishay.com/doc?95007			

### **Legal Disclaimer Notice**



Vishay

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